## NSN 5961-01-216-6186

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-216-6186 **Inclosure Material:** Plastic **Overall Length:** 5.5 millimeters **Terminal Length:** 14.0 millimeters **Overall Height:** 4.2 millimeters **Overall Width:** 5.2 millimeters **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current and 20.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 90.0 static forward current transfer ratio, common-emitter and 600.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No